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CCS K 83



**NATIONAL STANDARD OF THE
PEOPLE'S REPUBLIC OF CHINA**

GB/T 6495.4-1996

Replacing GB 6495-1986; GB 6493-1986

**Procedures for temperature and irradiance corrections to
measured I-V characteristics of crystalline silicon photovoltaic
devices**

(English Translation)

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What this standard covers

This standard specifies the temperature and irradiance corrections to measured IV characteristics of crystalline silicon photovoltaic devices, including the determination of the temperature coefficient of the internal series resistance and the line correction factor. These methods can be applied in the test used in the $\pm 30\%$ range of the auxiliary illumination.

Document data

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